

**Product data sheet** 

#### 1. General description

Planar passivated ultra sensitive gate Silicon Controlled Rectifier in a TO92 plastic package.

#### 2. Features and benefits

- Planar passivated for voltage ruggedness and reliability
- Ultra sensitive gate

## 3. Applications

- Electronic ballasts
- · Safety shut down and protection circuits
- Sensing circuits
- Smoke detectors
- Switched Mode Power Supplies

### 4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Absolute	maximum rating					
$V_{\text{DRM}}$	repetitive peak offstate voltage		-	-	400	V
$V_{RRM}$	repetitive peak reverse voltage		-	-	400	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>lead</sub> ≤ 92 °C; <u>Fig. 1</u>	-	-	0.5	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>lead</sub> ≤ 92 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	0.8	А
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	-	-	8	А
Static cha	racteristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 10 mA; T <sub>i</sub> = 25 °C; <u>Fig. 7</u>	-	3	12	μA

# **5. Pinning information**

Table 2. F	Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol					
1	A	anode							
2	G	gate	L, , , , , , , , , , , , , , , , , , ,	А Ң К					
3	К	cathode	() (	G sym037					

# 6. Ordering information

Table 3. Ordering information							
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date	
EC103D1	TO92	EC103D1,412	Bulk	1000	SOT54	14-Nov-2013	
EC103D1	TO92	EC103D1,116	Reel	2000	SOT54 wide pitch	14-Nov-2013	

# 7. Marking

Table 4. Marking codes							
	Type number	Marking codes					
	EC103D1	EC103D1					

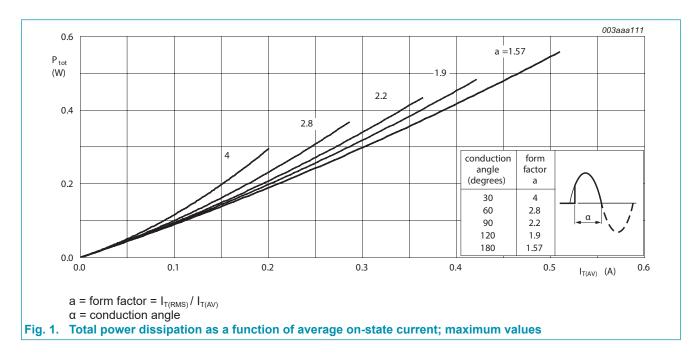
### 8. Limiting values

#### Table 5. Limiting values

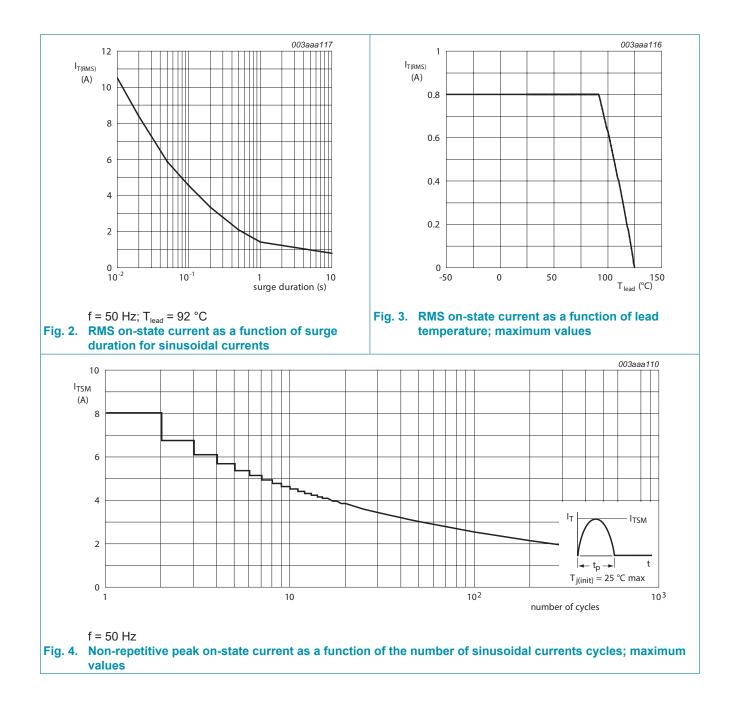
In accordance with the Absolute Maximum Rating System (IEC 60134).

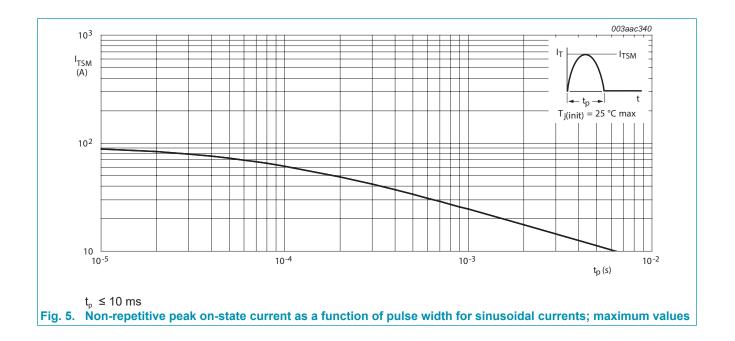
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage			-	400	V
$V_{RRM}$	repetitive peak reverse voltage			-	400	V
$I_{T(AV)}$	average on-state current	half sine wave; T <sub>lead</sub> ≤ 92 °C; <u>Fig. 1</u>		-	0.5	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>lead</sub> ≤ 92 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>		-	0.8	А
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5		-	8	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms		-	9	А
l <sup>2</sup> t	l <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN		-	0.32	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state current	$I_T = 2 \text{ A}; I_G = 10 \text{ mA}; \text{ d}I_G/\text{d}t = 100 \text{ mA}/\mu\text{s}$		-	50	A/µs
I <sub>GM</sub>	peak gate current			-	1	А
V <sub>RGM</sub>	peak reverse gate voltage			-	5	V
P <sub>GM</sub>	peak gate power			-	2	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period		-	0.1	W
T <sub>stg</sub>	storage temperature			-40	150	°C
T <sub>i</sub>	junction temperature		[1]	-	125	°C

[1] Operation above 110°C may require the use of a gate to cathode resistor of  $1k\Omega$  or less.



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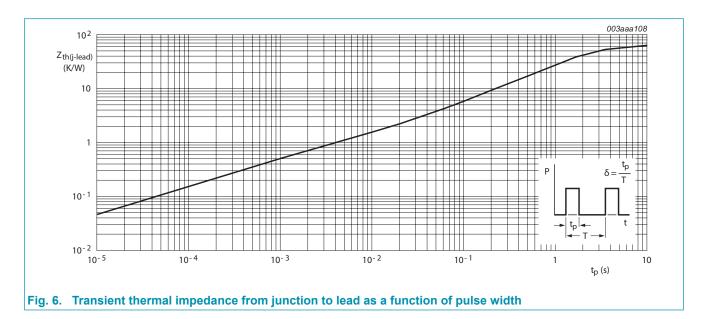


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## 9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	<u>Fig. 6</u>	-	-	60	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W

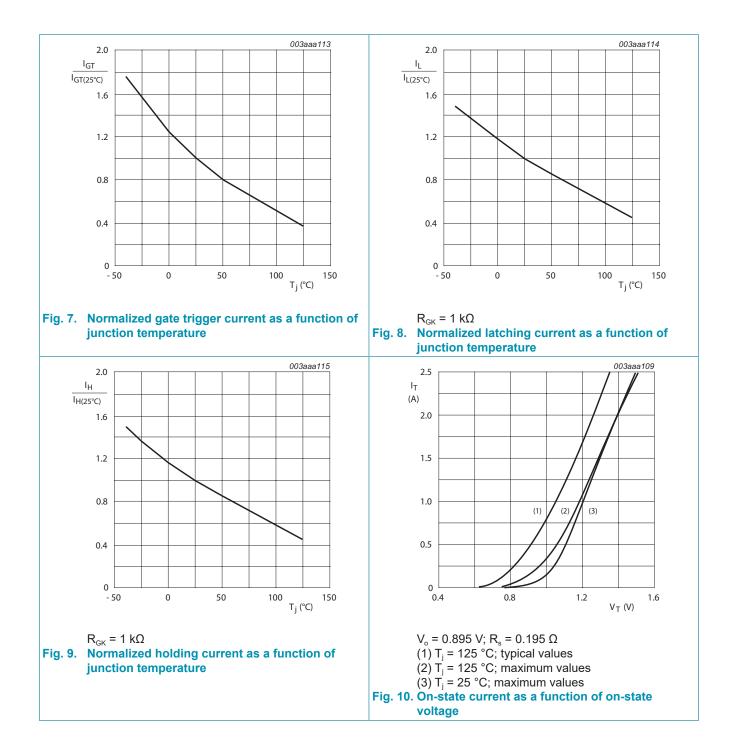


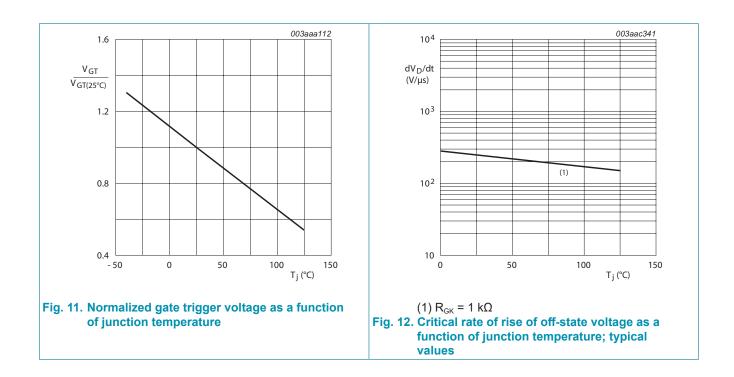
### **10. Characteristics**

	haracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 10 mA; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	3	12	μA
I <sub>L</sub>	latching current	$V_D$ = 12 V; I <sub>G</sub> = 0.5 mA; R <sub>GK</sub> = 1 kΩ; T <sub>j</sub> = 25 °C; Fig. 8	-	2	6	mA
I <sub>H</sub>	holding current	$V_{D}$ = 12 V; R <sub>GK</sub> = 1 kΩ; T <sub>j</sub> = 25 °C; Fig. 9	-	2	5	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.2	1.35	V
V <sub>GT</sub>	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 10 \text{ mA}; \text{ T}_{J} = 25 \text{ °C};$ Fig. 11	-	0.5	0.8	V
		V <sub>D</sub> = 400 V; I <sub>T</sub> = 10 mA; T <sub>j</sub> = 125 °C	0.2	0.3	-	V
I <sub>D</sub>	off-state current	$V_{\rm D}$ = 400 V; $R_{\rm GK}$ = 1 kΩ; $T_{\rm j}$ = 125 °C	-	0.05	0.1	mA
I <sub>R</sub>	reverse current	$V_{\rm D}$ = 400 V; $R_{\rm GK}$ = 1 kΩ; $T_{\rm j}$ = 125 °C	-	0.05	0.1	mA
Dynamic	characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage		-	150	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM} = 2 \text{ A}; V_D = 400 \text{ V}; I_G = 10 \text{ mA}; \text{ d}I_G/$ dt = 0.1 A/µs; T <sub>j</sub> = 25 °C	-	2	-	μs
t <sub>q</sub>	commutated turn-off time		-	100	-	μs

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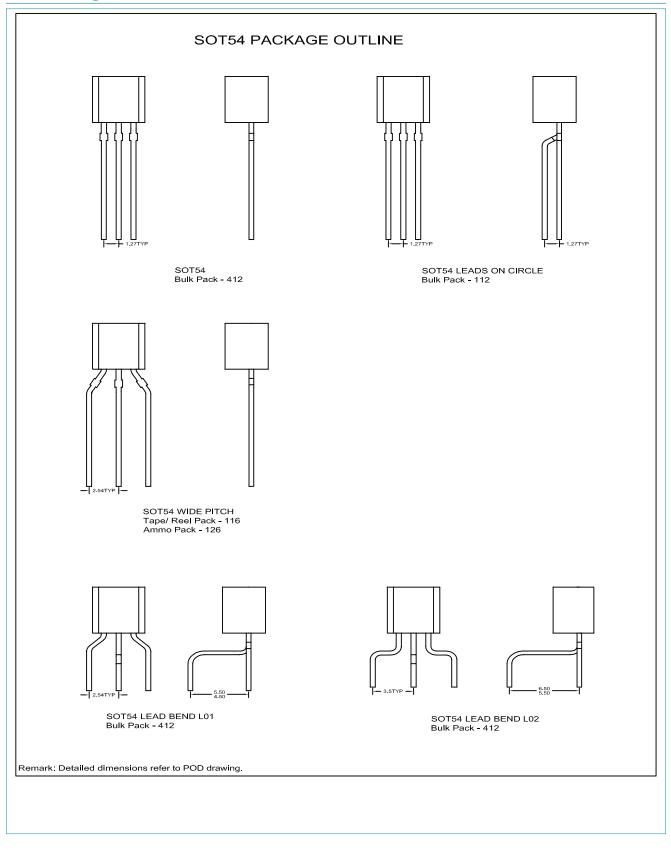


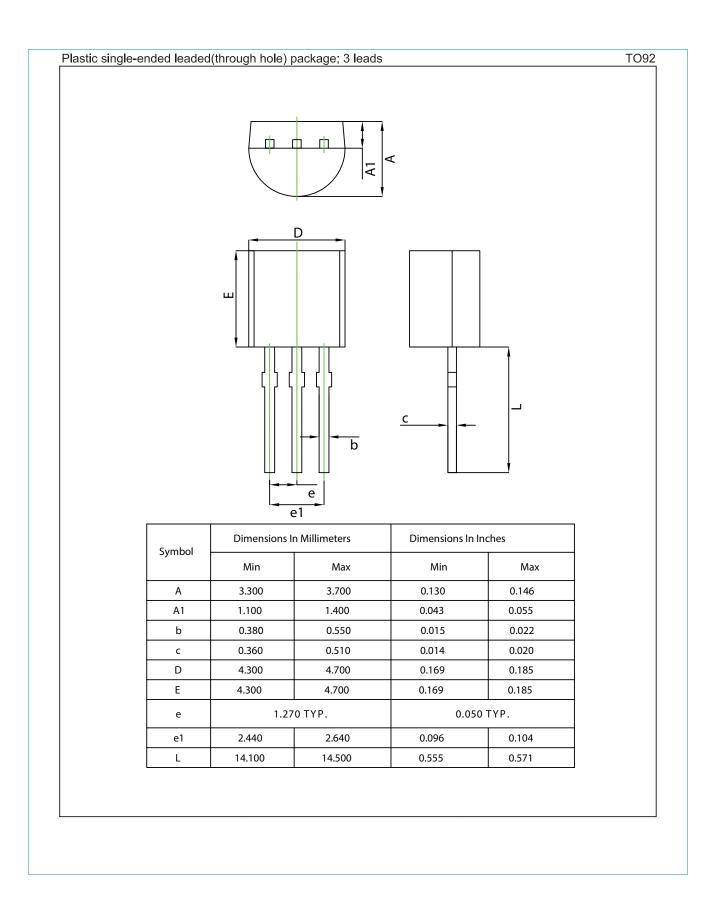


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# 11. Package outline





### 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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